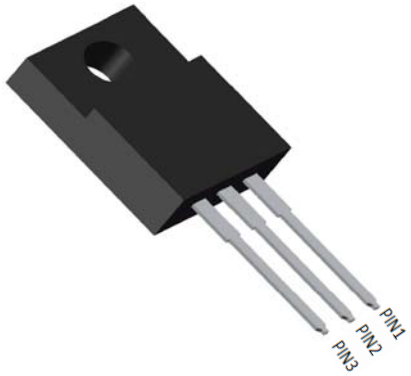
Schottky Diodes
MBR10100FCTS Through MBR10200FCTS

ITO-220AB



FEATURES

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

TYPICAL APPLICATIONS

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MECHANICAL DATA

- **Package**: ITO-220AB
  Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals**: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity**: As marked

MAXIMUM RATINGS (Ta=25℃ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR10100FCTS	MBR10150FCTS	MBR10200FCTS
Device marking code			MBR10100FCTS	MBR10150FCTS	MBR10200FCTS
Repetitive Peak Reverse Voltage	V_{RRM}	V	100	150	200
Average Rectified Output Current @60Hz sine wave, R-load, Tc=140℃	I_O	A	10		
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Ta=25℃	I_{FSM}	A	100		
Current Squared Time @1ms≤t≤8.3ms Tj=25℃,	I^2t	A^2s	41		
Storage Temperature	Tstg	℃	-55 ~ +175		
Junction Temperature	Tj	℃	-55 ~ +175		

ELECTRICAL CHARACTERISTICS (Ta=25℃ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR10100FCTS	MBR10150FCTS	MBR10200FCTS
Maximum instantaneous forward voltage drop per diode	V_{FM}	V	I_{FM}=5.0A	0.85	0.9	0.95
Maximum DC reverse current at rated DC blocking voltage per diode	I_{RRM1}	mA	$V_{RM}=V_{RRM}$ Ta=25℃	0.1		
	I_{RRM2}		$V_{RM}=V_{RRM}$ Ta=125℃	20		

THERMAL CHARACTERISTICS (Ta=25℃ Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MBR10100FCTS	MBR10150FCTS	MBR10200FCTS
Thermal Resistance	Between junction and case	$R_{\theta J-C}$	℃/W	4.0		

PACKAGING INFORMATION

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR10100FCTS THRU MBR10200FCTS	Approximate 1.9	50	1000	5000	Tube

■ CHARACTERISTICS (TYPICAL)

FIG1:Io -Tc Curve

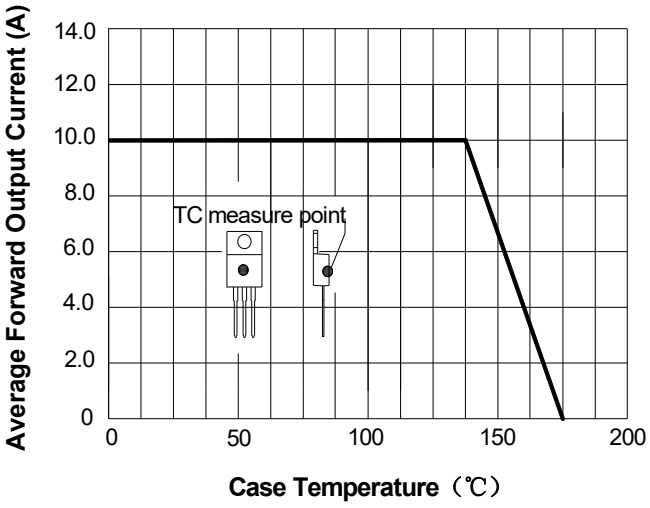


FIG2:Surge Forward Current Capability

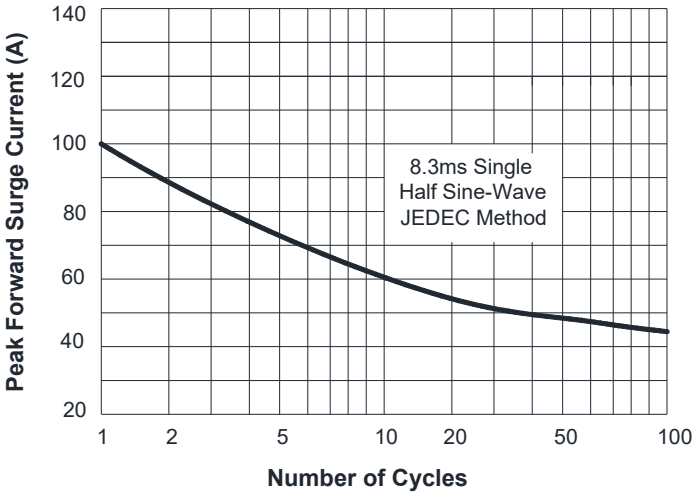


FIG3: Forward Voltage

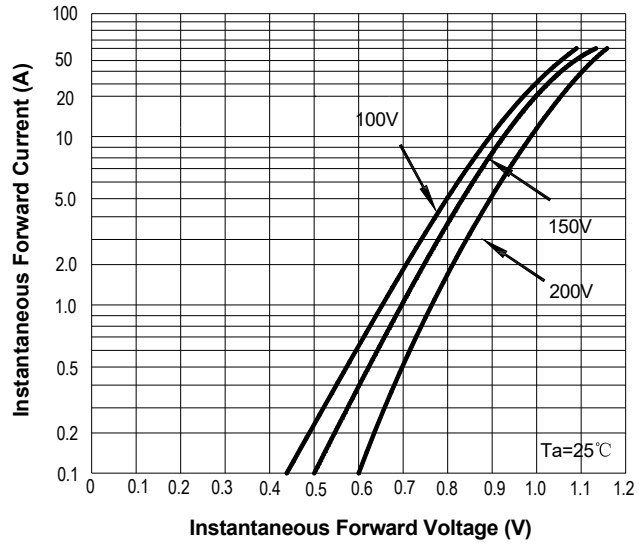
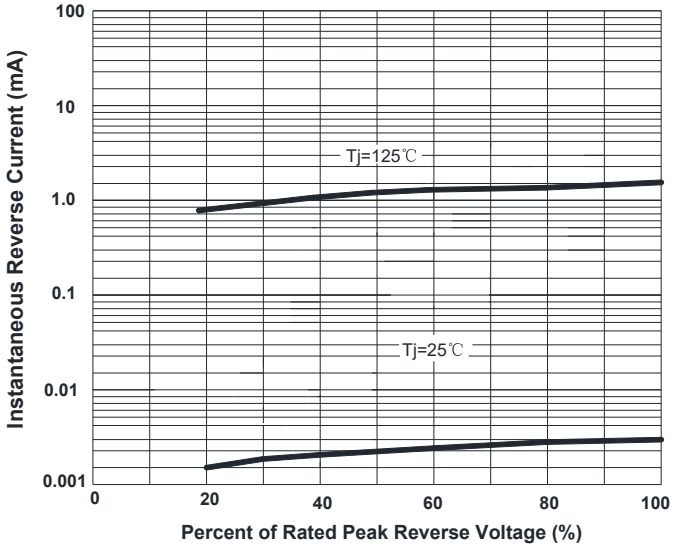
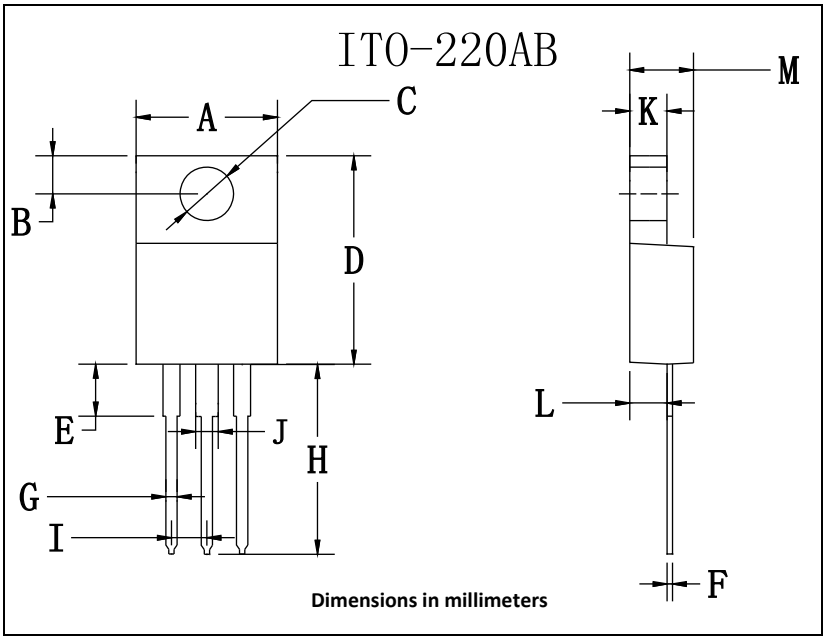


FIG.4: Instantaneous Reverse Characteristics



■ OUTLINE DIMENSIONS



ITO-220AB		
Dim	Min	Max
A	9.7	10.7
B	2.15	3.25
C	2.6	3.8
D	14.4	15.9
E	3.1	4.5
F	0.4	0.8
G	0.4	0.8
H	12.7	14.2
I	1.80	2.95
J	1.4	1.8
K	2.1	3.56
L	2.1	3.2
M	3.9	5.1